



DMT3006LFDFQ

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	7mΩ @ V <sub>GS</sub> = 10V	14.1A
30V	10mΩ @ V <sub>GS</sub> = 4.5V	11.8A
	15mΩ @ V <sub>GS</sub> = 3.7V	9.6A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Battery Management Application
- Power Management Functions
- DC-DC Converters

#### Features

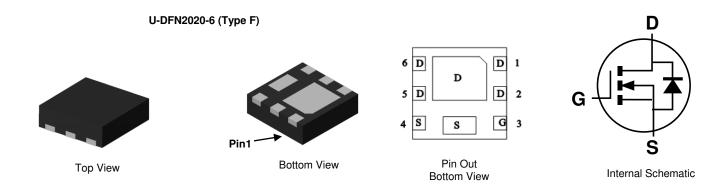
- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Low Gate Threshold Voltage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMT3006LFDFQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

N-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Reel Size (inches)	Quantity per Reel
DMT3006LFDFQ-7	7	3,000
DMT3006LFDFQ-13	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**

Site 1



6M = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020)M = Month (ex: 9 = September)

2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Н	I	J	K	L	М	N	0	Р	R	S	Т
Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
1	2	3	4	5	6	7	8	9	0	N	D
	H	H I	H I J	H I J K	H I J K L	H I J K L M		H I J K L M N O	H I J K L M N O P	H I J K L M N O P R	H I J K L M N O P R S

Site 2



6M= Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020)

W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key											
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028		
Code	0	1	2	3	4	5	6	7	8		
Week		1-26		27-52			53				
Code		A-Z		a-z			Z				
Internal Code	Sun	Mon		Tue	Wed	Thu		Fri	Sat		
Code	Т	U		V	W	Х		Y	Z		



### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	30	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	14.1 12.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		ldм	80	A	
Continuous Source-Drain Diode Current (Note 6) T <sub>A</sub> =			ls	2	A
Avalanche Current (Note 7) L = 0.1mH	las	25	A		
Avalanche Energy (Note 7) L = 0.1mH			Eas	31	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	155	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	60	°C/W
Thermal Resistance, Junction to Case (Note 6)	Tc = +25°C	Rejc	6.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)		•		•		·	
Drain-Source Breakdown Voltage	BVDSS	30	_	_	V	VGS = 0V, ID = 250µA	
Zero Gate Voltage Drain Current ( $T_J = +25^{\circ}C$ )	IDSS	—	_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)		•		•		·	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	1.3	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			5.8	7		VGS = 10V, ID = 9A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	7.8	10	mΩ	$V_{GS} = 4.5V, I_D = 8A$	
			9.3	15		VGS = 3.7V, ID = 5A	
Diode Forward Voltage	Vsd	_	0.7	1.0	V	$V_{GS} = 0V$ , $I_{S} = 2A$	
DYNAMIC CHARACTERISTICS (Note 9)		•				·	
Input Capacitance	Ciss	-	1,155	-		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	—	456	—	pF		
Reverse Transfer Capacitance	Crss	—	72	—			
Gate Resistance	Rg	_	1.6	—	Ω	$V_{DS} = 0V, V_{GS} = 0V,$ f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	QG	—	16.7	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	QG	_	8.4	—	-0		
Gate-Source Charge	Qgs	—	2.2	—	nC	$V_{DD} = 15V, I_D = 9A$	
Gate-Drain Charge	Q <sub>GD</sub>	—	3.5	—			
Turn-On Delay Time	td(ON)	—	3.5	—			
Turn-On Rise Time	tR	_	5.5	_		$V_{DD} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	tD(OFF)	_	13.5	—	ns	$R_G = 3\Omega$ , $I_D = 9A$	
Turn-Off Fall Time	tF	—	4.6	—			
Reverse Recovery Time	trr	—	19.3	_	ns		
Reverse Recovery Charge	QRR	—	8.6	-	nC	- I <sub>F</sub> = 1.5A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

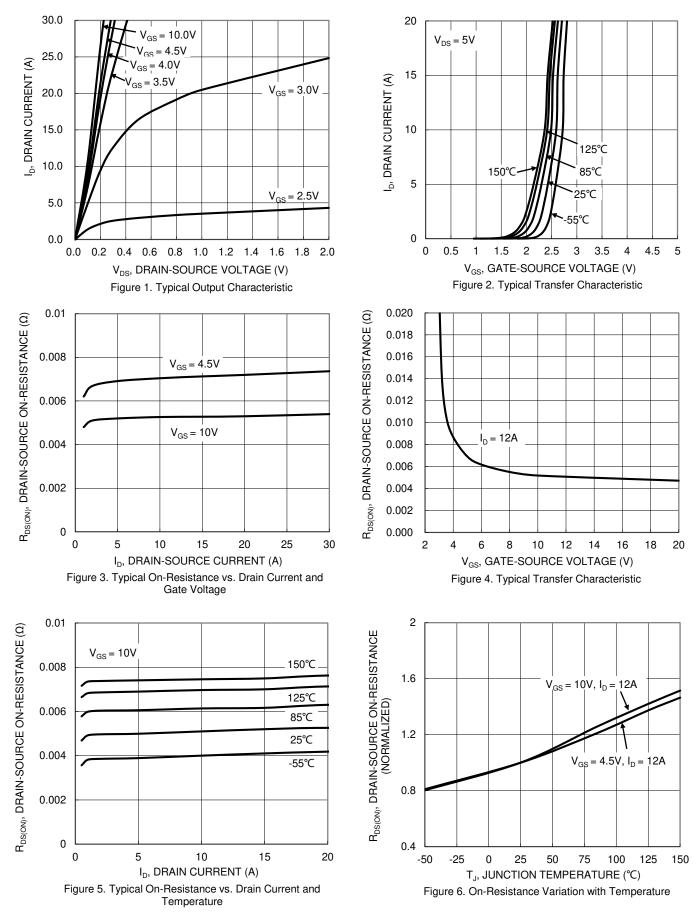
7. IAS and EAS ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



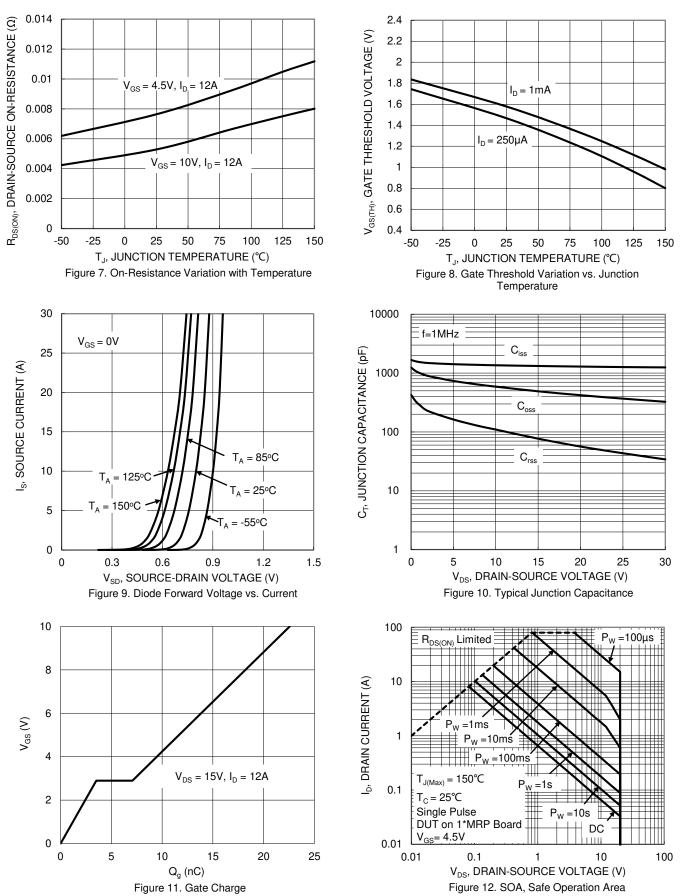
## DMT3006LFDFQ



DMT3006LFDFQ Datasheet number: DS41967 Rev. 2 - 2

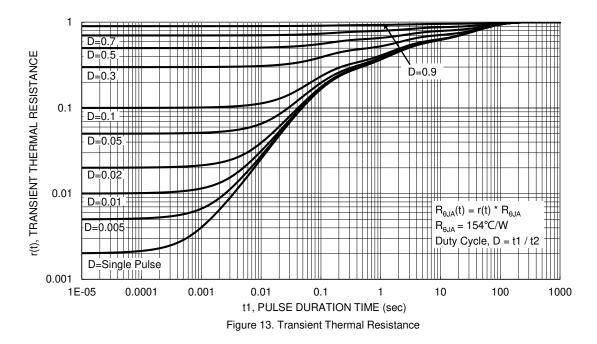


# DMT3006LFDFQ





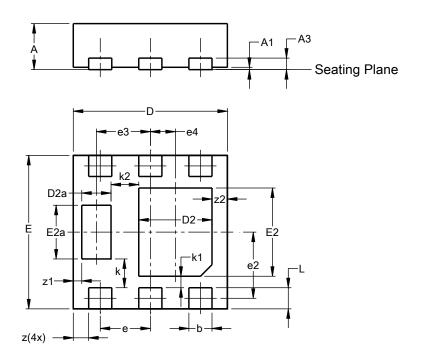






### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



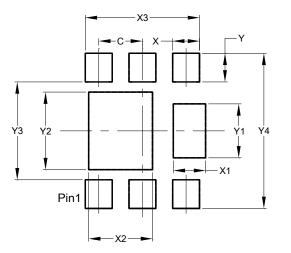
	U-DFN2020-6									
-	(Type F)									
Dim	Min	Max	Тур							
Α	0.57	0.63	0.60							
A1	0.00	0.05	0.03							
A3	-	-	0.15							
b	0.25	0.35	0.30							
D	1.95	2.05	2.00							
D2	0.85	1.05	0.95							
D2a	0.33	0.43	0.38							
E	1.95	2.05	2.00							
E2	1.05	1.25	1.15							
E2a	0.65	0.75	0.70							
е		0.65 BS	С							
e2	0.863 BSC									
e3		0.70 BS	С							
e4	0	0.325 BSC								
k		0.37 BSC								
k1	0.15 BSC									
k2	0.36 BSC									
L	0.225 0.325 0.275									
z		0.20 BS	С							
z1	0	).110 BS	SC							
z2		0.20 BS	С							
All C	)imens	ions in	mm							

#### U-DFN2020-6 (Type F)

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com